

Technology Concepts for Next Generation VLA  
Workshop, Pasadena, April 9, 2015

## **LNA's for the 1.2 to 55 GHz Range**

Sander Weinreb

1. Semiconductor technology applicable to cryogenic LNA's
2. Examples of discrete and integrated circuits
3. LNA for 1.2 to 8.4 GHz
4. Prototype LNA for 8 to 55 GHz
5. System noise

# Cryogenic LNA Noise is Limited by the Transistors Available from Semiconductor Foundries

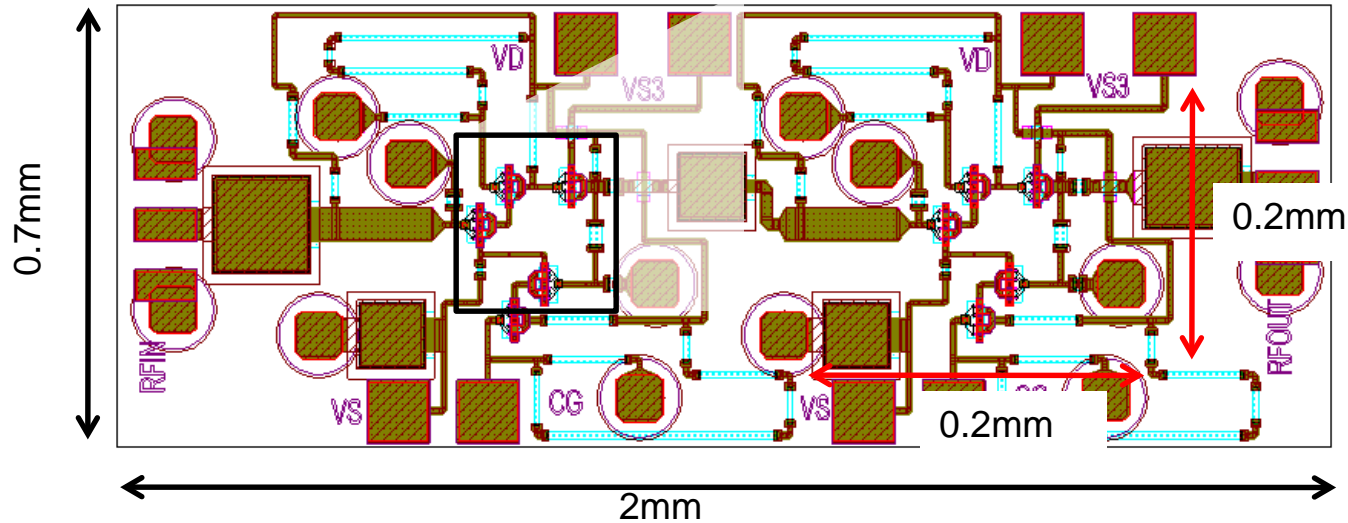
- Both HEMT and HBT transistors are used in radio astronomy LNA's
- Amplifiers can be constructed either from discrete transistors (MICs) or from monolithic integrated circuits. (MMICs)

<b>Semi-conductor</b>	<b>Application</b>	<b>Key Players</b>	<b>Development Pace</b>	<b>Key Factor</b>
InP HEMT	Cooled, > 5 GHz	Northrop, HRL, Teledyne, IAF Chalmers	Slow	Yield,
GaAs HEMT	Cooled > 5 GHz	WIN, Triquint OMMIC	Slow	Noise
SiGe HBT	Cooled < 5 GHz	ST, IBM, NXP, Jazz, Infineon	Moderate	Beta
CMOS FET	Cooled < 20 GHz	Intel, IBM, TSMC	High	Needs Tests

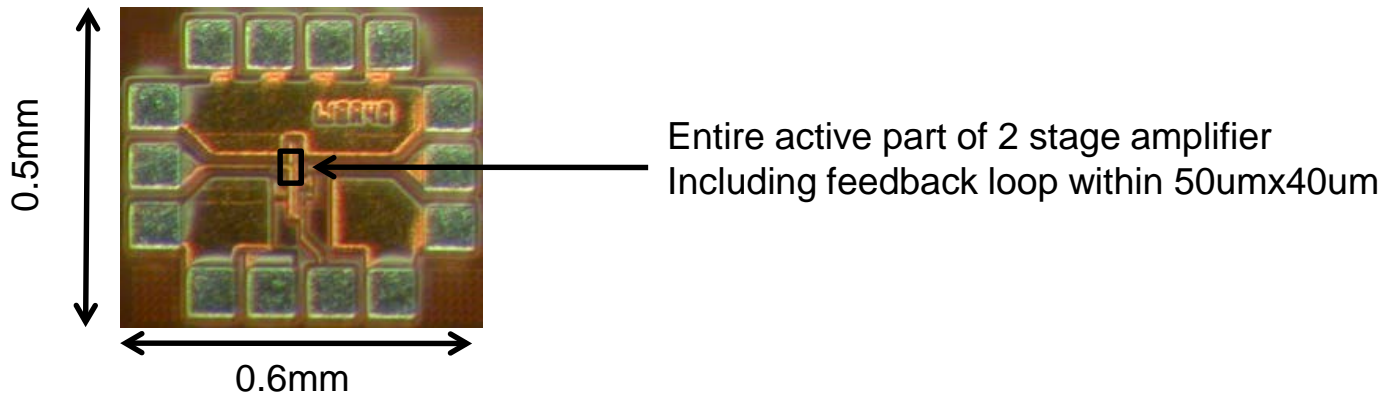
# Monolithic Integrated Circuit (MMIC) Amplifiers

## Examples of HEMT and SiGe Chips

InP  
HEMT  
MMIC

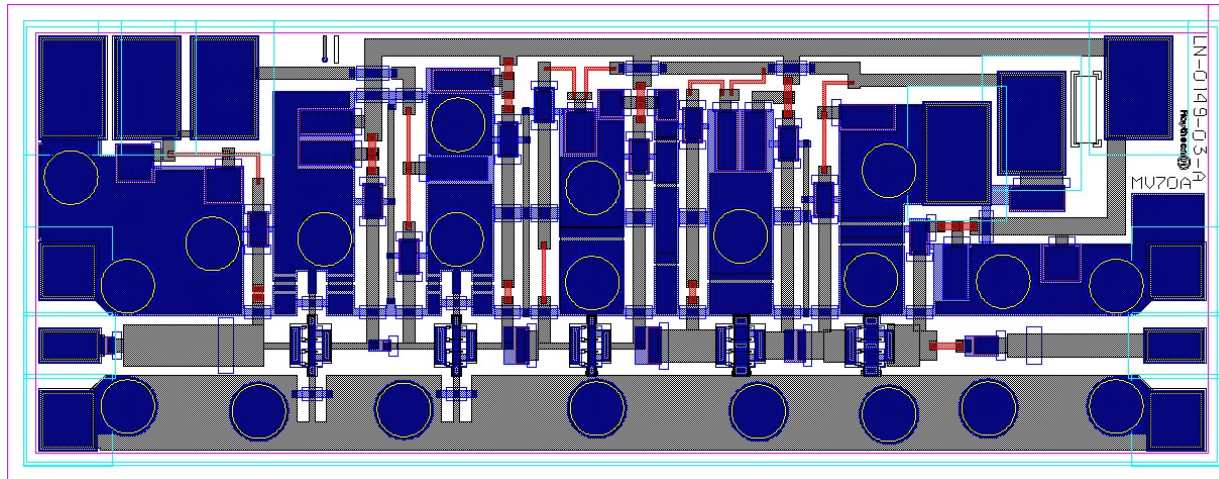


SiGe  
MMIC

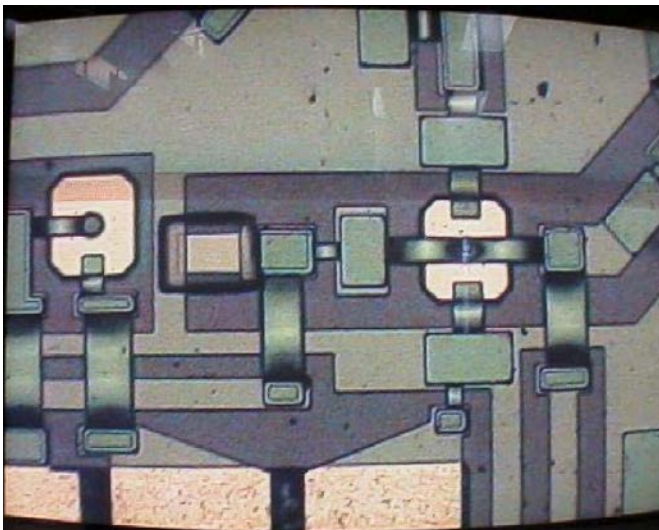


Assuming an effective dielectric constant of 9, a 0.5mm path length will contribute a 90° phase shift at 40GHz! SiGe and CMOS processes allow for much more compact feedback loops!

# Monolithic Millimeter-Wave Integrated Circuits



Example of a MMIC layout with transmission lines, capacitors, resistors, and active devices on a single substrate. Above chip's dimensions are 2.0 x 0.74 x 0.1 mm.



Advantages	Disadvantages
reduced mass and volume	low-Q passive elements
repeatable performance	limited power handling
low cost in large quantities	long design iteration time
fine-controlled dimensions through photolithography	limited post-fabrication tuning
easy to mass produce	requires specialized test and evaluation equipment
	difficult assembly and interconnection



# Caltech ST Microelectronics SiGe Reticule, 2010

Size : 2.3 x 4.1 mm = 9.43 mm<sup>2</sup>

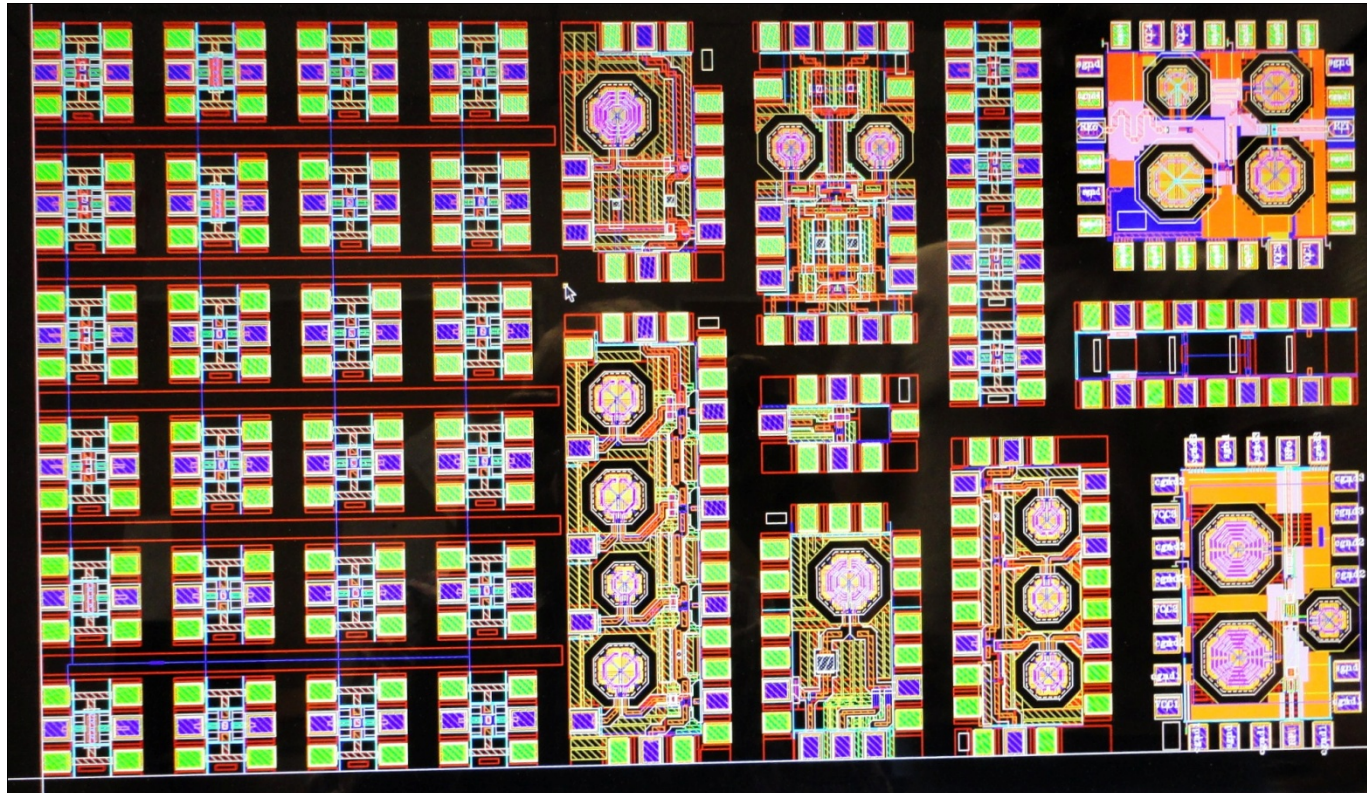
24 Discrete Transistors  
0.3 x 0.3 mm

1-2 GHz

Dif LNA

CALS

11-26 LNA



R Tests  
Salycide  
N+Poly  
P+Poly

16 – 5x 15um=75um  
4 – 4x5x12um =240um  
2 – 2x10um=20um  
2 – 1x10um=10um

WBA20  
0.1 -12  
GHz

ASU Low  
Power

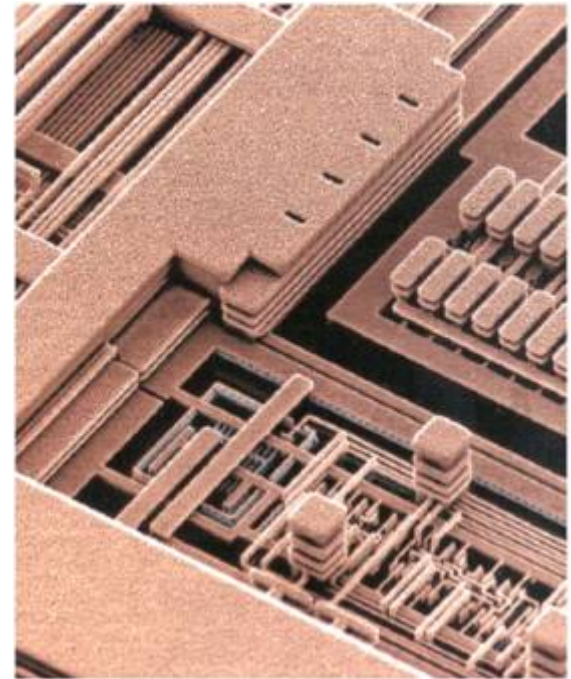
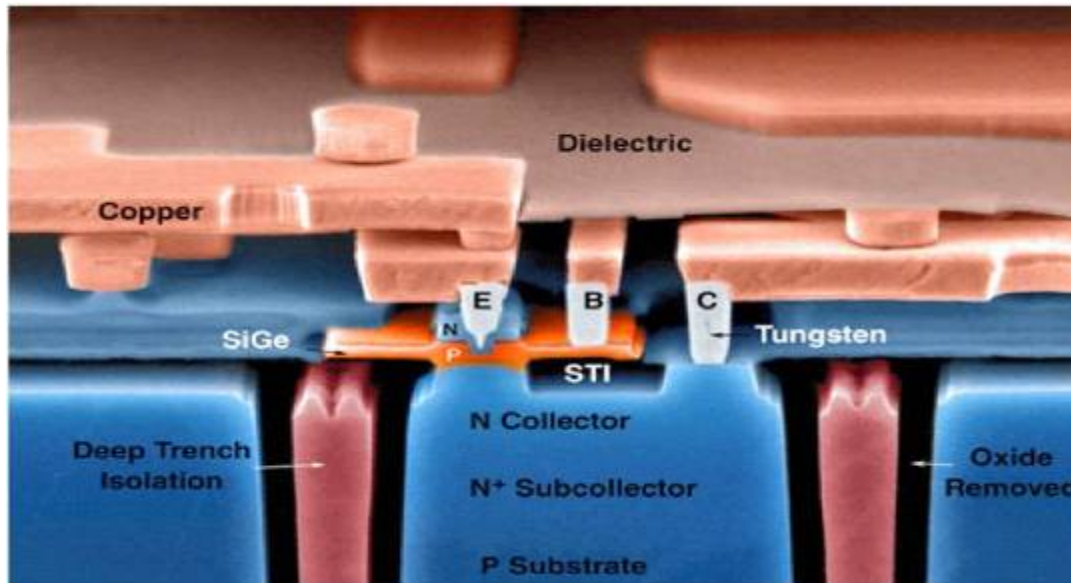
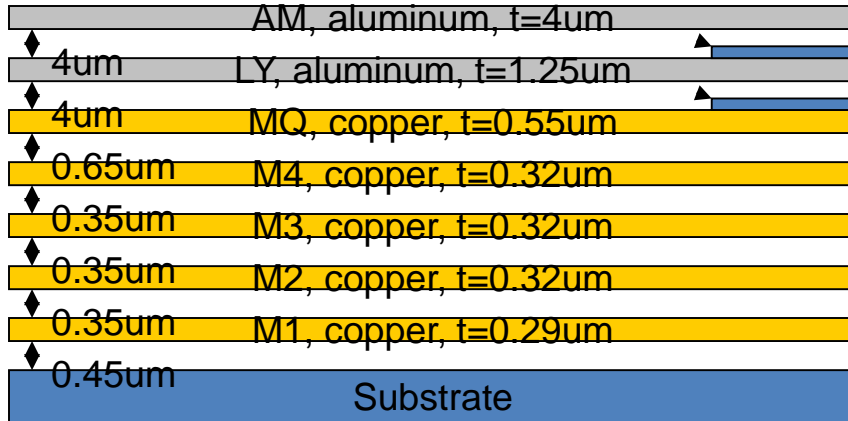
WBA21  
0.1-12  
GHz

0.5-3 GHz

LNA's for ngVLA

# SiGe IC Cross-Section

Many interconnect layers enable complex circuits

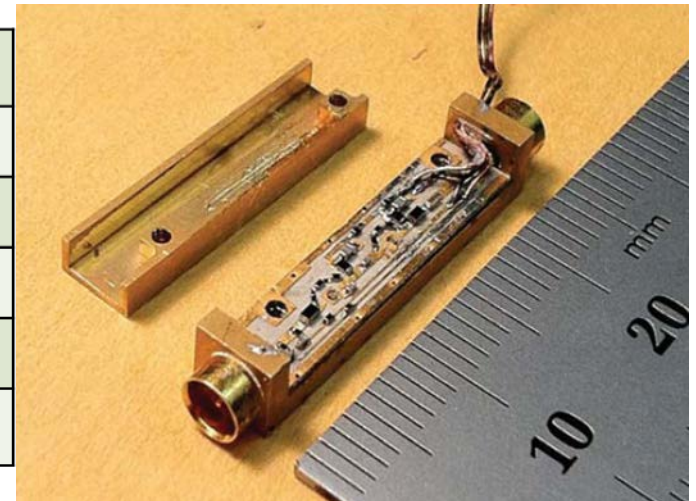




# Wideband Cryogenic LNA Development at Caltech

- In a 10 year period over 1200 cryogenic LNA's in the 0.1 to 50 GHz range have been supplied by Caltech to international radio astronomy and quantum physics research groups.
- The LNA's incorporate InP, GaAs, and SiGe transistors and integrated circuits developed in 4 Ph.D. theses at Caltech
- Cryogenic LNA's for 75 to 115 GHz have been developed at Caltech and JPL and have achieved noise temperatures as low as 25K
- Data and a photograph of one of a 1 to 25 GHz LNA is shown below.

Country or Institution and Number Sold			
Japan	83	US	335
Germany	77	Caltech/JPL	72
Korea	63	Harvard/SAO	39
China	51	Berkeley	33
France	47	Yale	13

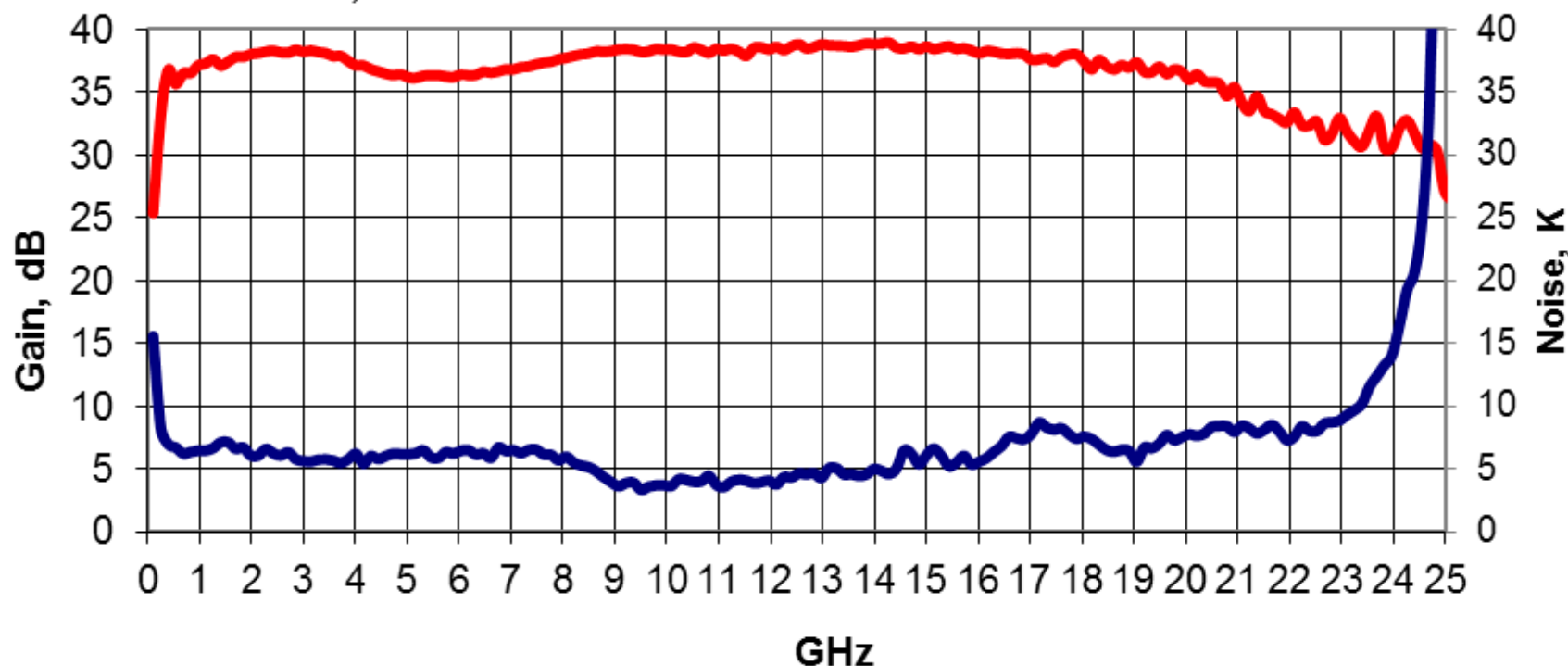


# Caltech LNA for ngVLA 1.2 to 8.4 GHz Band

- Noise <6K from 0.8 to 16 GHz
- Utilizes OMMIC GaAs MMIC available in large quantities
- Amplifier is very stable and repeatable; over 20 in use
- Input power for 1dB gain compression is -36 dBm



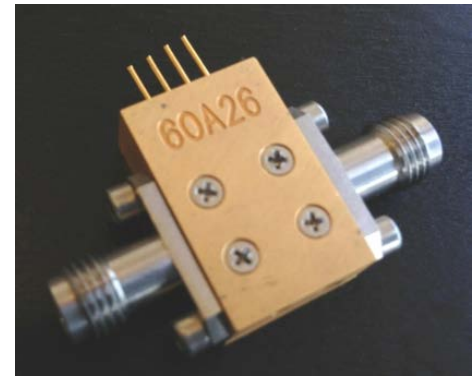
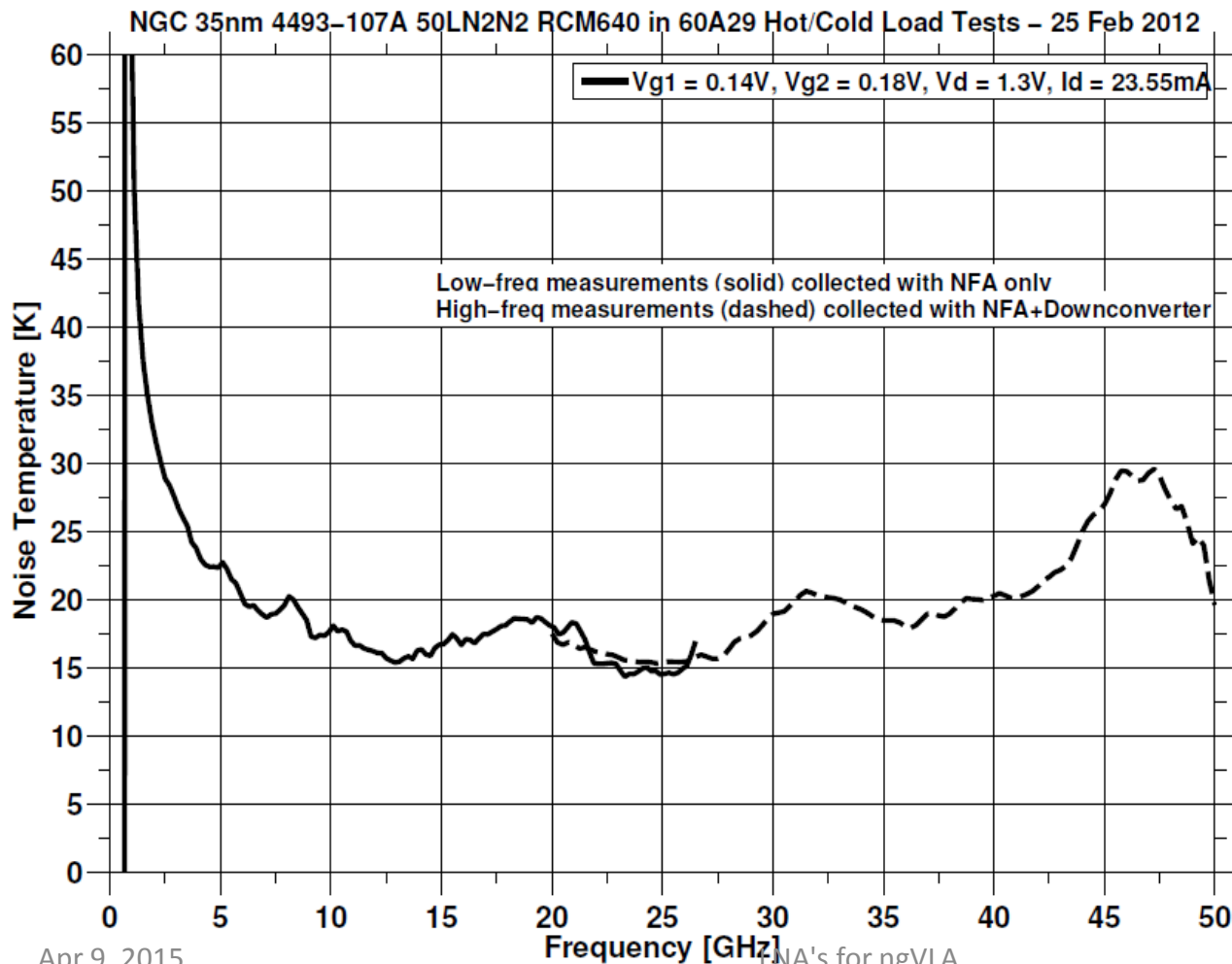
**OMMIC WBA118B in SN804D Noise and Gain at 19k**  
Vd=1.0V 24mA; Vg1= +.5V Vg2=+.5V with 11:1 Divider  
Jul 21, 2014 File 3174 With PCB112B IMN with 10K Quartz





# Prototype of ngVLA 8 to 55 GHz LNA

- An 8 to 50 GHz MMIC InP HEMT LNA was designed and tested at Caltech in 2012 and show potential for under 20K noise.
- Amplifier utilizes a Northrop InP MMIC process



# Total System Noise Estimate

Noise, K, due to component	Remarks	Tsys 1.4 GHz	Tsys 10 GHz	Tsys 40 GHz	Tsys 80 GHz
Sky	Background + atmosphere	4	6	20	55
Spillover & Blockage	Reduce with offset antenna	10	7	7	7
Feed loss	Estimate 0.3 dB @80K for 1.4 GHz @20K for 8-116 GHz	5	1	3	3
Window loss	Mylar windows	2	3	3	3
Feed to LNA	0.30 dB	5	1	2	1
LNA	Robust LNA measured at connector	3	6	15	25
Total	Estimate, +/- 5K	29	24	50	94

# Atmospheric Noise is Appreciable for the ngVLA

- Noise above 40 GHz is weather and altitude dependent; curves below are for zenith at sea level
- The 55-70 GHz range is not covered by receivers.

